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(54) **IMPROVED MIRROR AND CAVITY DESIGNS FOR SAMPLED-GRATING DISTRIBUTED BRAGG REFLECTOR LASERS**

VERBESSERTE SPIEGEL UND RESONATOR AUSFÜHRUNGEN FÜR VERTEILTEN BRAGG-REFLEKTOR MIT TASTGITTER

MODELES DE MIROIR ET DE CAVITE AMELIORES DESTINES A DES LASERS POUR REFLECTEUR DE BRAGG REPARTIS A RESEAU DE DIFFRACTION ECHANTILLONNE

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